

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	545	(pocket adj implant)	US-PGPUB; USPAT	OR	ON	2005/05/12 09:12
L2	203	1 same (source drain) same type	US-PGPUB; USPAT	OR	ON	2005/05/12 09:13
L3	187	2 and "12"	US-PGPUB; USPAT	OR	ON	2005/05/12 09:14
L4	15	2 same (self adj align\$8)	US-PGPUB; USPAT	OR	ON	2005/05/12 10:06
L5	23	(damascene inlaid "in-laid") same ((etchstop (etch\$6 near stop\$6)) with nitride) same (cmos nmos pmos mosfet fet transistor)	US-PGPUB; USPAT	OR	ON	2005/05/12 11:39
L7	859	(spacer sidewall (side adj wall)) near2 sacrificial	US-PGPUB; USPAT	OR	ON	2005/05/12 11:40
L8	8	7 same ((heav\$6 near2 (doped implant\$6)) with first)	US-PGPUB; USPAT	OR	ON	2005/05/12 11:44
L9	50	7 and (438/301.ccls. 438/303.ccls. 438/675.ccls. 438/786.ccls. 438/791.ccls. 427/249.15.ccls. 427/255.27.ccls. 427/255.28.ccls. 427/255.393.ccls. 427/255.394. ccls.)	US-PGPUB; USPAT	OR	ON	2005/05/12 11:46